SHEET 1 OF 1

INFORMATION DISCLOSURE CITATION IN AN APPLICATION					ATTY. DOCKET NO. 57454-322		SERIAL NO.		
			APPLICANT Hideto HIDAKA						
	(PTO-1	•	FILING DATE January 18, 2002		GROUP				
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			ļ				Yes	No	
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Mam m / 2/12/2003									

EXAMPLER / Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.